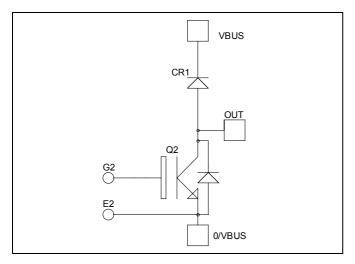
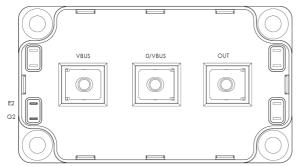


## Boost chopper Trench + Field Stop IGBT3 Power Module







#### Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

#### **Features**

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1700	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	400	
$I_{\rm C}$	Continuous Conector Current	$T_C = 80$ °C	300	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	600	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Maximum Power Dissipation	$T_C = 25$ °C	1660	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	600A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				750	μΑ
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_C = 300A$	$T_j = 25$ °C		2.0	2.4	V
			$T_j = 125$ °C		2.4		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 5mA$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

**Dynamic Characteristics** 

•	Characteristic	Test Conditions	Test Conditions		Тур	Max	Unit
$C_{ies}$	Input Capacitance	$V_{GE} = 0V$			26.5		nF
$C_{oes}$	Output Capacitance	$V_{CE} = 25V$	$V_{CE} = 25V$		1.1		
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz			0.88		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			370		
$T_{r}$	Rise Time	$V_{GE} = 15V$			40		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 300A$ $R_{G} = 2.2\Omega$			650		ns
$T_{\mathrm{f}}$	Fall Time				180		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch		400		ns	
$T_{r}$	Rise Time	$\begin{array}{l} V_{GE} = 15V \\ V_{Bus} = 900V \\ I_{C} = 300A \\ R_{G} = 2.2\Omega \end{array}$			50		
$T_{d(off)}$	Turn-off Delay Time				800		
$T_{\mathrm{f}}$	Fall Time				300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 900V$	$T_j = 125$ °C		96		ma I
$E_{\text{off}}$	Turn-off Switching Energy	$I_C = 300A$ $R_G = 2.2\Omega$	$T_j = 125$ °C		94		mJ

Chopper diode ratings and characteristics
Symbol Characteristic To

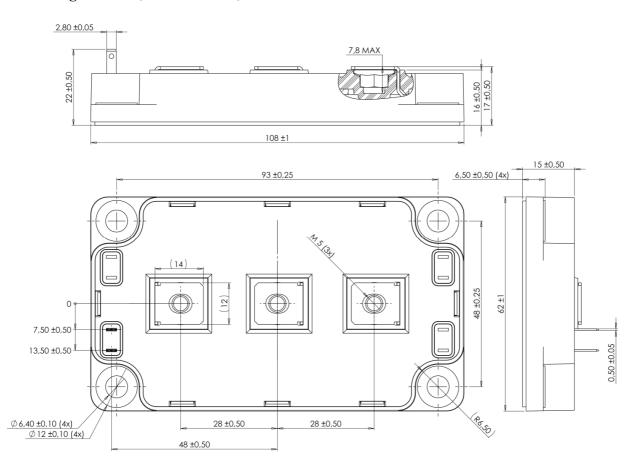
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1700			V
Ţ	Maximum Reverse Leakage Current	V <sub>R</sub> =1700V	$T_j = 25$ °C			750	4
$I_{RM}$			$T_j = 125$ °C			1000	μA
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		300		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 300A$	$T_i = 25$ °C		1.8	2.2	V
<b>*</b> F			$T_{i} = 125^{\circ}C$		1.9		
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 300A$ $V_R = 900V$ $di/dt = 3200A/\mu s$	$T_j = 25^{\circ}C$		385		- ns
rr			$T_{j} = 125^{\circ}C$		490		
	Reverse Recovery Charge		$T_j = 25^{\circ}C$		76		μС
$Q_{rr}$			$T_{j} = 125^{\circ}C$		124		μС
$E_{r}$	Reverse Recovery Energy		$T_j = 25^{\circ}C$		35		mJ
$\mathbf{E}_{\mathbf{r}}$			$T_{j} = 125^{\circ}C$		70		1113



## Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
$R_{\text{thJC}}$	Junction to Case Thermal Resistance  IGBT  Diode		IGBT			0.075	°C/W
			Diode			0.14	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range Storage Temperature Range			-40		150	
$T_{STG}$				-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

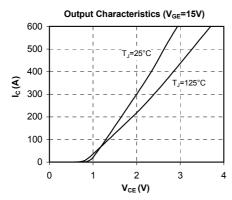
### SP6 Package outline (dimensions in mm)

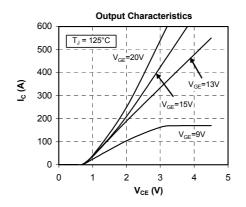


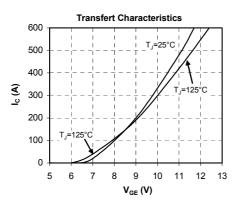
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

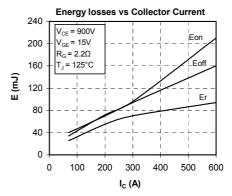


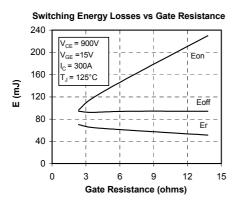
### **Typical Performance Curve**

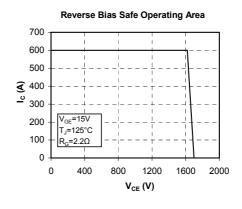


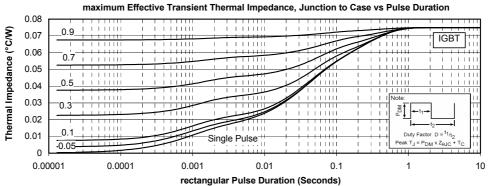




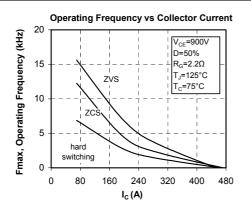


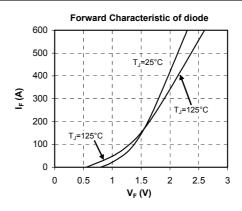


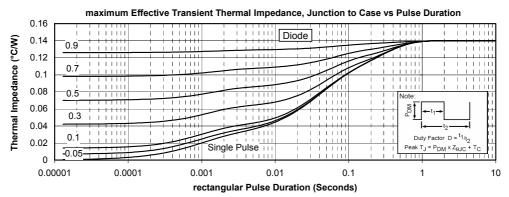














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